rfmd.com

SGA-2163(Z)

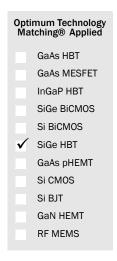
DC to 5000 MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER

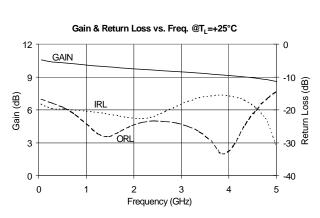
RFMD Green, RoHS Compliant, Pb-Free (Z Part Number)
Package: SOT-363



Product Description

The SGA-2163 is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high F_T and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.





Features

- Broadband Operation: DC to 5000 MHz
- Cascadable 50Ω
- Operates from Single Supply
- Low Thermal Resistance Package

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

| Davamatav | Specification | | | Hoit | Condition | |
|-------------------------------------|---------------|------|--------------|------|-----------------|--|
| Parameter | Min. | Тур. | Max. | Unit | Condition | |
| Small Signal Gain | 9.5 | 10.5 | 11.5 | dB | 850MHz | |
| | | 9.8 | | dB | 1950MHz | |
| | | 9.6 | | dB | 2400 MHz | |
| Output Power at 1dB Compression | | 7.1 | | dBm | 850MHz | |
| | | 6.2 | | dBm | 1950MHz | |
| Output Third Intercept Point | | 21.0 | | dBm | 850MHz | |
| | | 18.0 | | dBm | 1950MHz | |
| Bandwidth Determined by Return Loss | | 5000 | | MHz | >10dB | |
| Input Return Loss | | 22.5 | | dB | 1950MHz | |
| Output Return Loss | | 24.8 | | dB | 1950MHz | |
| Noise Figure | | 4.4 | | dB | 1950MHz | |
| Device Operating Voltage | 1.9 | 2.2 | 2.5 | V | | |
| Device Operating Current | 17 | 20 | 23 | mA | | |
| Thermal Resistance | | 255 | por topo = 1 | °C/W | junction - lead | |

Test Conditions: $V_S = 5V$, $I_D = 20$ mA Typ., OIP_3 Tone Spacing = 1MHz, P_{OUT} per tone = 10 dBm, $R_{BIAS} = 140\Omega$, $T_L = 25$ °C, $Z_S = Z_L = 50\Omega$



Absolute Maximum Ratings

| Parameter | Rating | Unit |
|-----------------------------------------------|------------|------|
| Max Device Current (I _D) | 40 | mA |
| Max Device Voltage (V _D) | 4 | V |
| Max RF Input Power | +18 | dBm |
| Max Junction Temperature (T _J) | +150 | °C |
| Operating Temperature Range (T _L) | -40 to +85 | °C |
| Max Storage Temperature | +150 | °C |

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression: $I_DV_D < (T_J - T_L) / R_{TH}, j - I_J > I_J >$



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

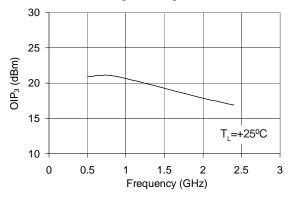
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Typical Performance at Key Operating Frequencies

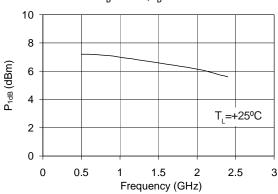
| Parameter | Unit | 100 MHz | 500MHz | 850MHz | 1950MHz | 2400 MHz | 3500 MHz |
|------------------------------------|------|---------|--------|--------|---------|----------|----------|
| Small Signal Gain | dB | 10.7 | 10.6 | 10.5 | 9.8 | 9.6 | 9.3 |
| Output Third Order Intercept Point | dBm | | 20.9 | 21.0 | 18.0 | 16.9 | |
| Output Power at 1dB Compression | dBm | | 7.2 | 7.1 | 6.2 | 5.6 | |
| Input Return Loss | dB | 18.7 | 19.8 | 20.3 | 22.5 | 22.1 | 16.0 |
| Output Return Loss | dB | 17.2 | 19.1 | 22.3 | 24.8 | 23.4 | 27.6 |
| Reverse Isolation | dB | 15.6 | 15.4 | 15.5 | 16.1 | 16.4 | 16.9 |
| Noise Figure | dB | | 4.2 | 4.1 | 4.4 | 4.8 | |

 $Test \ Conditions: V_S = 5V, \ I_D = 20 \ mA \ Typ., \ OIP_3 \ Tone \ Spacing = 1 \ MHz, \ P_{OUT} \ per \ tone = -10 \ dBm, \ R_{BIAS} = 140 \ \Omega, \ T_L = 25 \ ^\circ C, \ Z_S = Z_L = 50 \ \Omega$

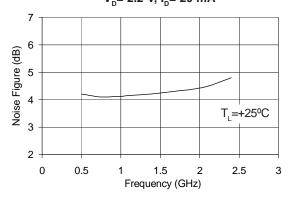
OIP_3 vs. Frequency $V_D = 2.2 \text{ V, } I_D = 20 \text{ mA}$



P_{1dB} vs. Frequency $V_D = 2.2 \text{ V}, I_D = 20 \text{ mA}$

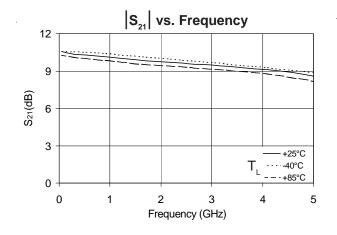


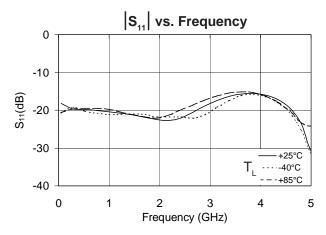
Noise Figure vs. Frequency $V_D = 2.2 \text{ V}, I_D = 20 \text{ mA}$

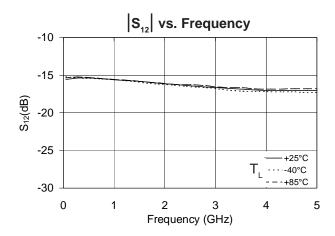


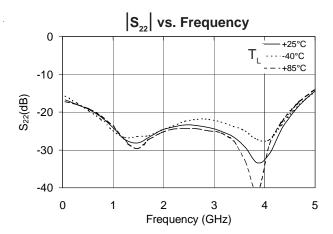


Typical RF Performance Over Temperature (Bias: V_D=2.2V, I_D=20 mA (Typ.))





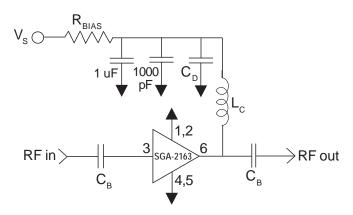


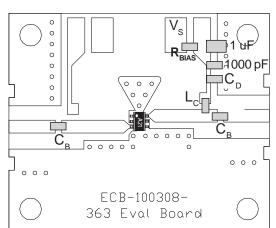


| Pin | Function | Description |
|-------|-------------|---------------------------------------------------------------------------------------------------------------------------------|
| 3 | RF IN | RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation. |
| 1, 2, | GND | Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible. |
| 4, 5 | | oie. |
| 6 | RF OUT/BIAS | RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation. |



Basic Application Circuit





Application Circuit Element Values

| Reference | | Frequency (Mhz) | | | | | | |
|----------------|--------|-----------------|-------|-------|-------|--|--|--|
| Designator | 500 | 850 | 1950 | 2400 | 3500 | | | |
| C _B | 220 pF | 100 pF | 68 pF | 56 pF | 39 pF | | | |
| C _D | 100 pF | 68 pF | 22 pF | 22 pF | 15 pF | | | |
| L _c | 68 nH | 33 nH | 22 nH | 18 nH | 15 nH | | | |

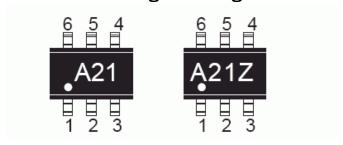
| Recommended Bias Resistor Values for I_D =20mA R_{BIAS} =(V_S - V_D) / I_D | | | | |
|----------------------------------------------------------------------------------------|-----|-----|-----|------|
| Supply Voltage(V _S) | 5 V | 6 V | 8 V | 10 V |
| R_{BAS} 140Ω 200Ω 300Ω 390Ω | | | | |
| Note: R _{BIAS} provides DC bias stability over temperature. | | | | |

Mounting Instructions

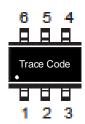
- Use a large ground pad area near device pins 1, 2,
 and 5 with many plated through-holes as shown.
- We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.



Package Drawing.



Alternate Marking with Trace Code Only



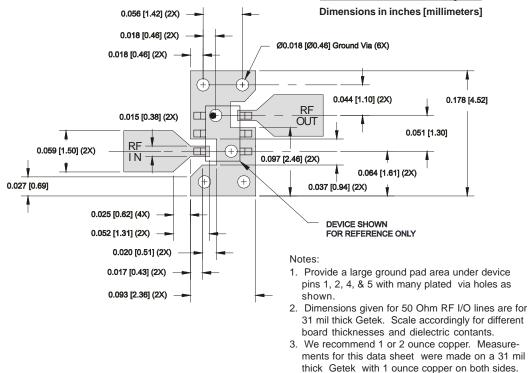
Ordering Information

| Part Number | Reel Size | Devices/Reel |
|-------------|-----------|--------------|
| SGA-2163 | 7" | 3000 |
| SGA-2163Z | 7" | 3000 |



SOT-363 PCB Pad Layout

SOT-363 PCB Pad Layout



Package Dimensions

